



**TDA2822M**

## DUAL LOW-VOLTAGE POWER AMPLIFIER

- SUPPLY VOLTAGE DOWN TO 1.8V
- LOW CROSSOVER DISTORSION
- LOW QUIESCENT CURRENT
- BRIDGE OR STEREO CONFIGURATION



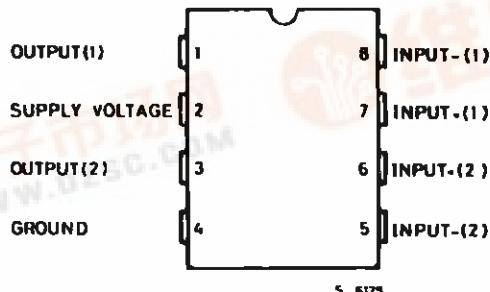
MINIDIP

ORDERING NUMBER : TDA2822M

### DESCRIPTION

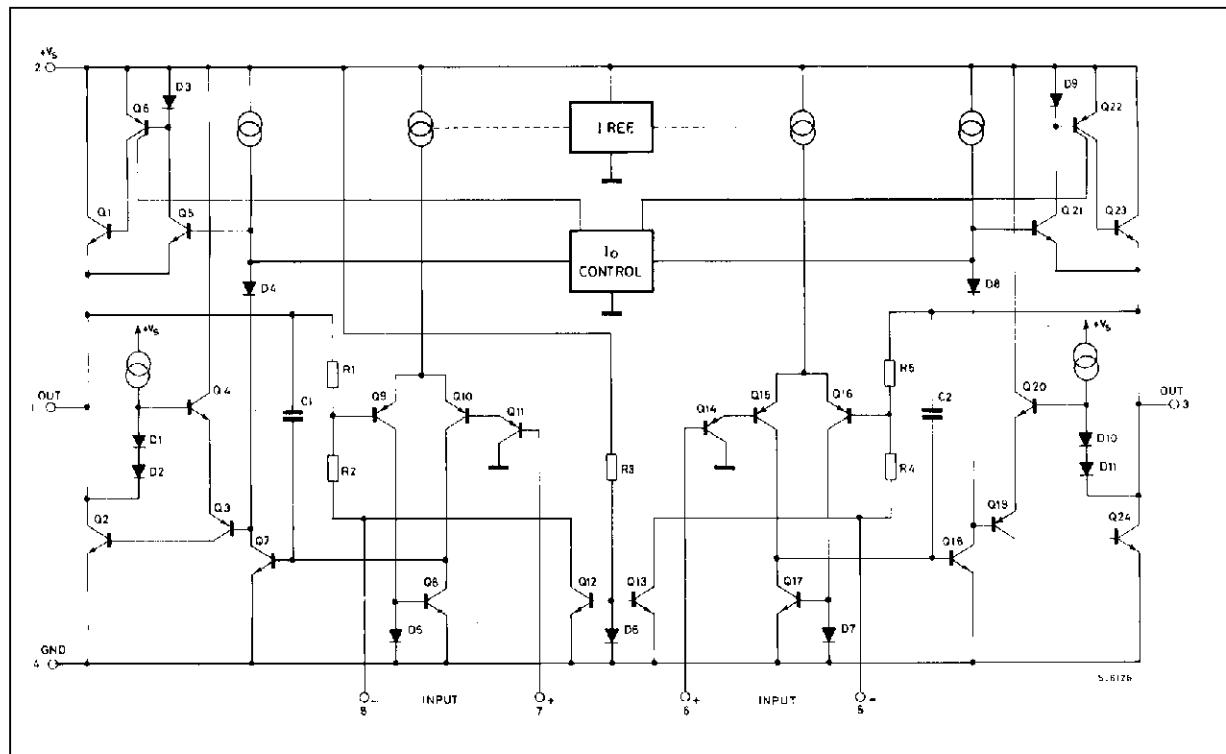
The TDA2822M is a monolithic integrated circuit in 8 lead Minidip package. It is intended for use as dual audio power amplifier in portable cassette players and radios.

### PIN CONNECTION (Top view)



## TDA2822M

### SCHEMATIC DIAGRAM



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>s</sub>	Supply Voltage	15	V
I <sub>o</sub>	Peak Output Current	1	A
P <sub>tot</sub>	Total Power Dissipation at T <sub>amb</sub> = 50 °C at T <sub>case</sub> = 50 °C	1 1.4	W W
T <sub>stg</sub> , T <sub>j</sub>	Storage and Junction Temperature	- 40, + 150	°C

### THERMAL DATA

Symbol	Parameter	Value	Unit
R <sub>th j-amb</sub>	Thermal Resistance Junction-ambient	Max.	100
R <sub>th j-case</sub>	Thermal Resistance Junction-pin (4)	Max.	70

**ELECTRICAL CHARACTERISTICS** ( $V_S = 6V$ ,  $T_{amb} = 25^\circ C$ , unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
<b>STEREO</b> (test circuit of Figure 1)							
$V_S$	Supply Voltage			1.8		15	V
$V_o$	Quiescent Output Voltage	$V_S = 3V$			2.7 1.2		V V
$I_d$	Quiescent Drain Current				6	9	mA
$I_b$	Input Bias Current				100		nA
$P_o$	Output Power (each channel) ( $f = 1\text{kHz}$ , $d = 10\%$ )	$R_L = 32\Omega$ $R_L = 16\Omega$ $R_L = 8\Omega$ $R_L = 4\Omega$	$V_S = 9V$ $V_S = 6V$ $V_S = 4.5V$ $V_S = 3V$ $V_S = 2V$ $V_S = 6V$ $V_S = 9V$ $V_S = 6V$ $V_S = 6V$ $V_S = 4.5V$ $V_S = 3V$	90 15 170 300 450	300 60 20 5 220 1000 380 650 320 110		mW
$d$	Distortion ( $f = 1\text{kHz}$ )	$R_L = 32\Omega$ $R_L = 16\Omega$ $R_L = 8\Omega$	$P_o = 40\text{mW}$ $P_o = 75\text{mW}$ $P_o = 150\text{mW}$		0.2 0.2 0.2		% % %
$G_V$	Closed Loop Voltage Gain	$f = 1\text{kHz}$		36	39	41	dB
$\Delta G_V$	Channel Balance					$\pm 1$	dB
$R_i$	Input Resistance	$f = 1\text{kHz}$		100			k $\Omega$
$e_N$	Total Input Noise	$R_s = 10\text{k}\Omega$	B = Curve A B = 22Hz to 22kHz		2 2.5		$\mu\text{V}$ $\mu\text{V}$
SVR	Supply Voltage Rejection	$f = 100\text{Hz}$ , $C_1 = C_2 = 100\mu\text{F}$		24	30		dB
$C_s$	Channel Separation	$f = 1\text{kHz}$			50		dB

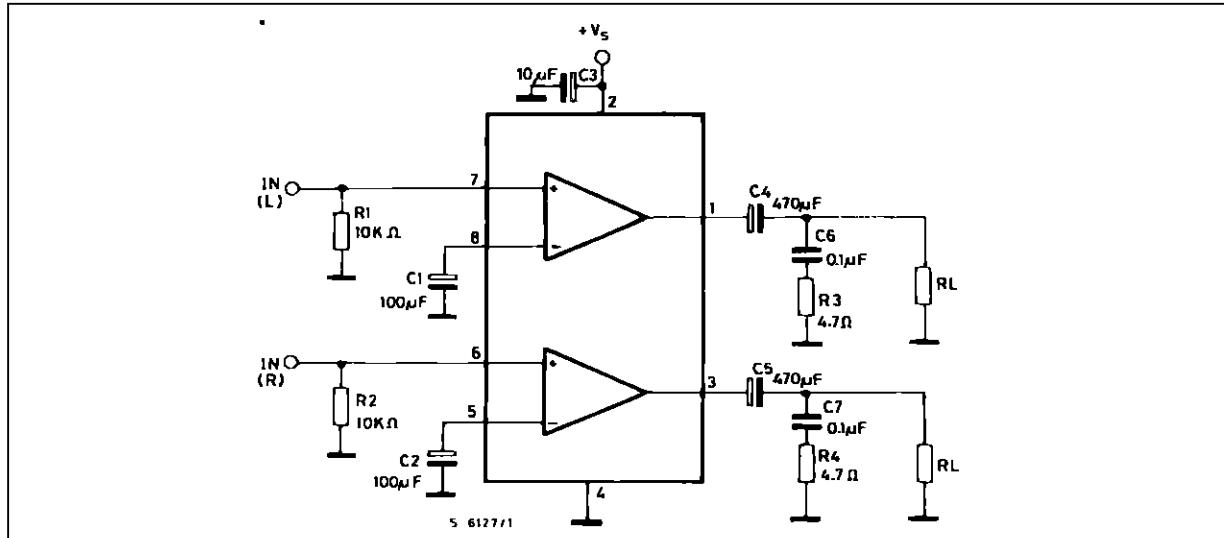
**BRIDGE** (test circuit of Figure 2)

Symbol	Parameter			1.8		15	V
$I_d$	Quiescent Drain Current	$R_L = \infty$			6	9	mA
$V_{os}$	Output Offset Voltage (between the outputs)	$R_L = 8\Omega$				$\pm 50$	mV
$I_b$	Input Bias Current				100		nA
$P_o$	Output Power ( $f = 1\text{kHz}$ , $d = 10\%$ )	$R_L = 32\Omega$ $R_L = 16\Omega$ $R_L = 8\Omega$ $R_L = 4\Omega$	$V_S = 9V$ $V_S = 6V$ $V_S = 4.5V$ $V_S = 3V$ $V_S = 2V$ $V_S = 9V$ $V_S = 6V$ $V_S = 3V$ $V_S = 6V$ $V_S = 4.5V$ $V_S = 3V$ $V_S = 2V$	320 50 900 200	1000 200 1350 1000 400 200 800 120 700 220 350 80		mW
$d$	Distortion	$P_o = 0.5\text{W}$ , $R_L = 8\Omega$ , $f = 1\text{kHz}$			0.2		%
$G_V$	Closed Loop Voltage Gain	$f = 1\text{kHz}$			39		dB
$R_i$	Input Resistance	$f = 1\text{kHz}$		100			k $\Omega$
$e_N$	Total Input Noise	$R_s = 10\text{k}\Omega$	B = Curve A B = 22Hz to 22kHz		2.5 3		$\mu\text{V}$ $\mu\text{V}$
SVR	Supply Voltage Rejection	$f = 100\text{Hz}$			40		dB
$B$	Power Bandwidth (-3dB)	$R_L = 8\Omega$ , $P_o = 1\text{W}$			120		kHz

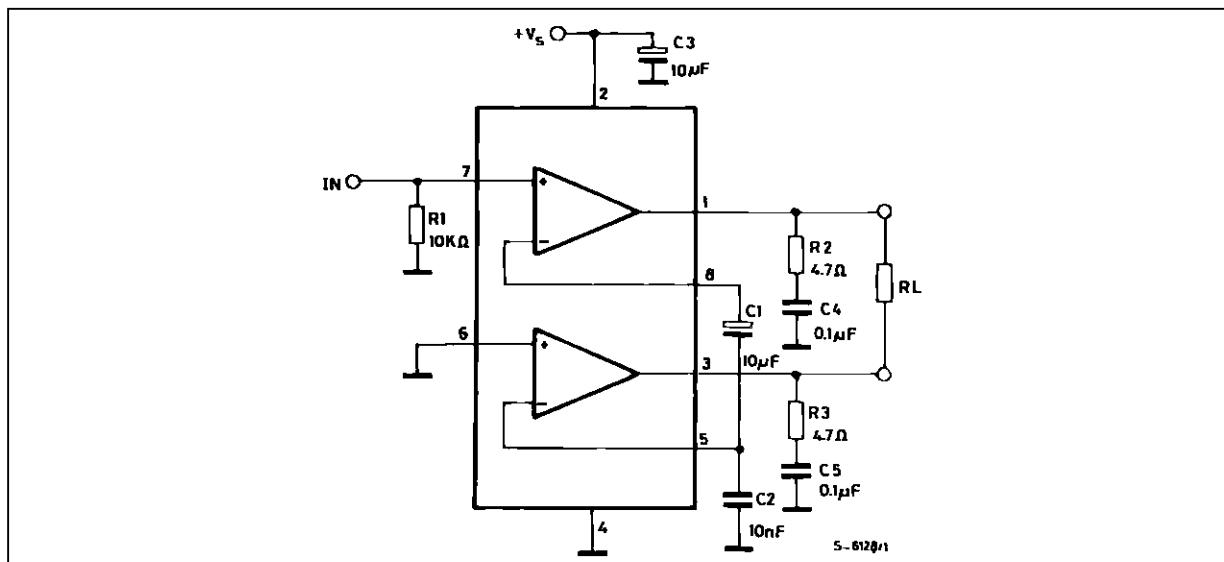
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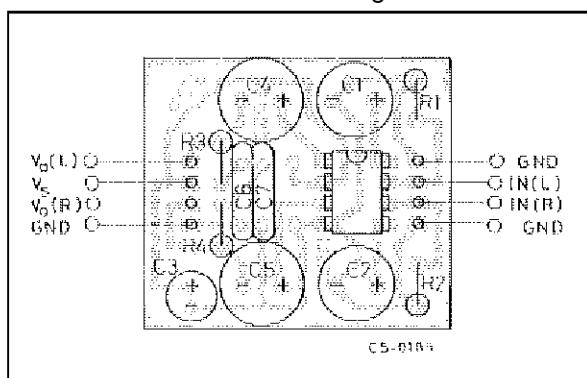
**Figure 1 : Test Circuit (Stereo)**



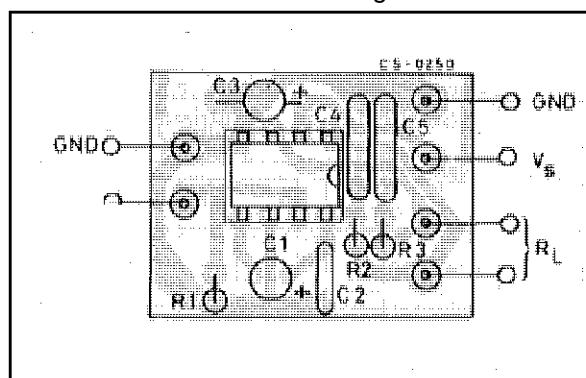
**Figure 2 : Test Circuit (Bridge)**



**Figure 3 : P.C. Board and Components Layout of the Circuit of Figure 1**



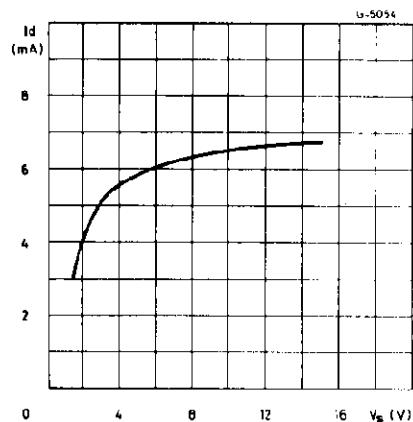
**Figure 4 : P.C. Board and Components Layout of the Circuit of Figure 2**



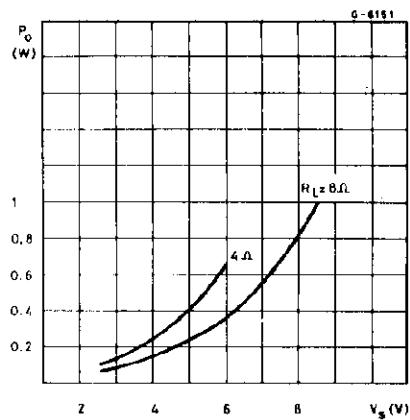
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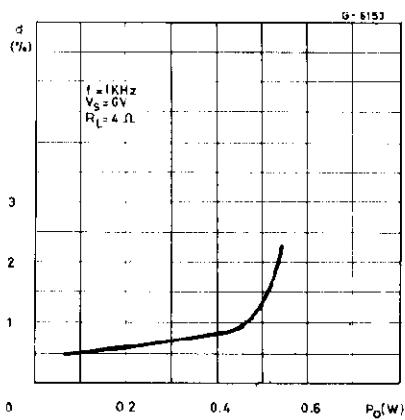
**Figure 5 :** Quiescent Current versus Supply Voltage



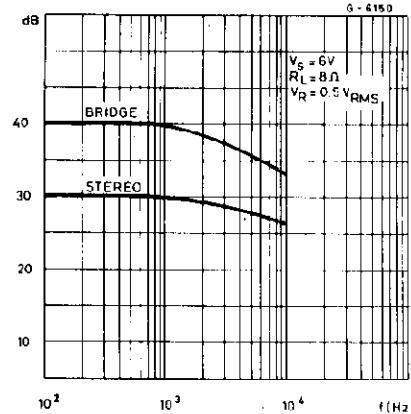
**Figure 7 :** Output Power versus Supply Voltage (THD = 10%, f = 1kHz Stereo)



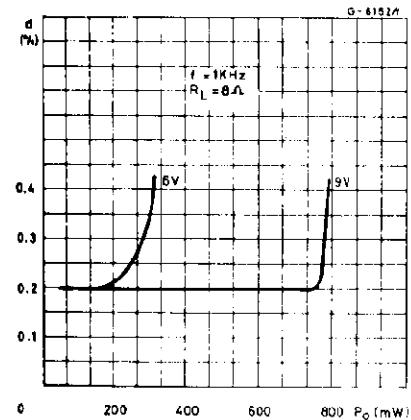
**Figure 9 :** Distortion versus Output Power (Stereo)



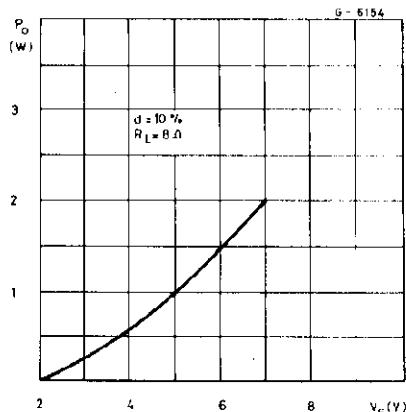
**Figure 6 :** Supply Voltage Rejection versus Frequency



**Figure 8 :** Distortion versus Output Power (Stereo)



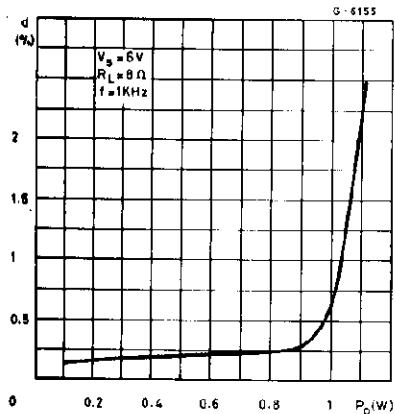
**Figure 10 :** Output Power versus Supply Voltage (Bridge)



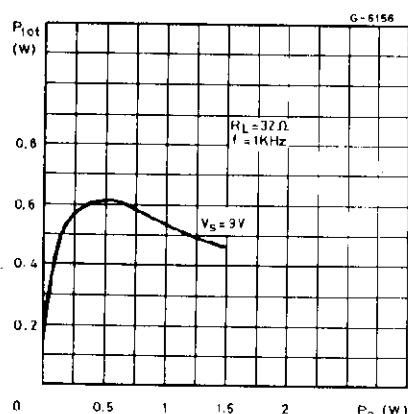
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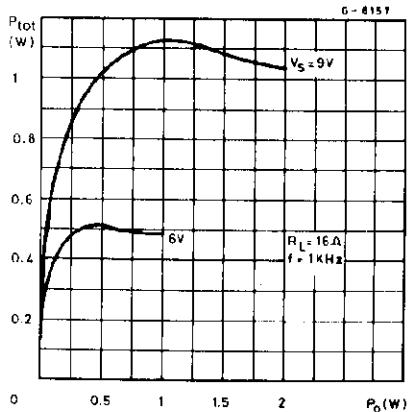
**Figure 11 :** Distortion versus Output Power (Bridge)



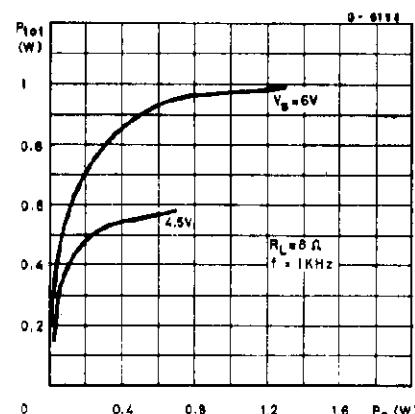
**Figure 12 :** Total Power Dissipation versus Output Power (Bridge)



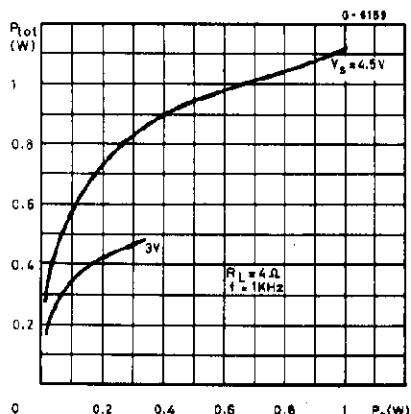
**Figure 13 :** Total Power Dissipation versus Output Power (Bridge)



**Figure 14 :** Total Power Dissipation versus Output Power (Bridge)

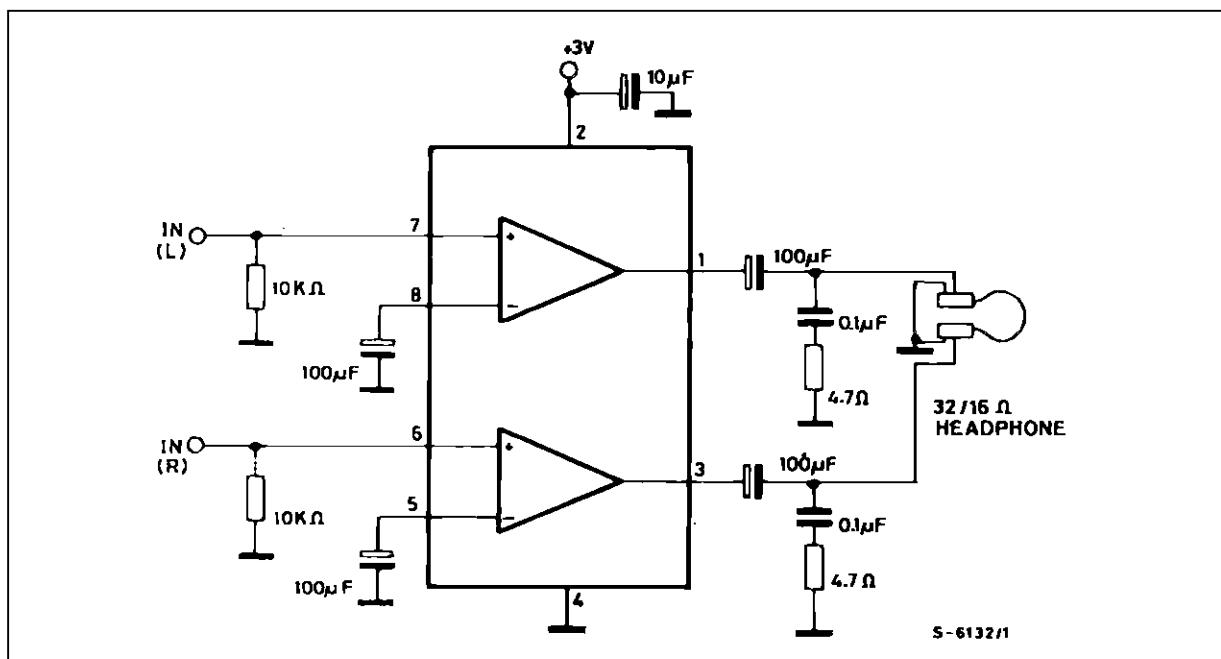


**Figure 15 :** Total Power Dissipation versus Output Power (Bridge)

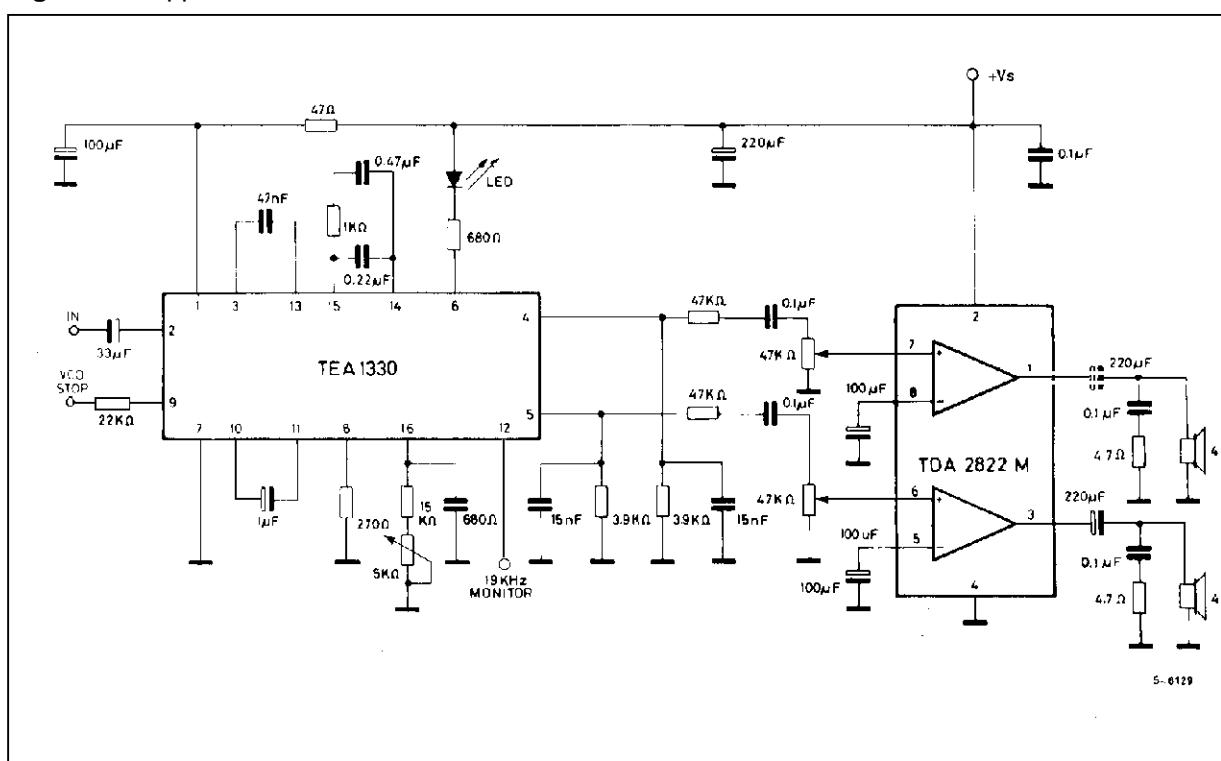


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**Figure 16 :** Typical Application in Portable Players



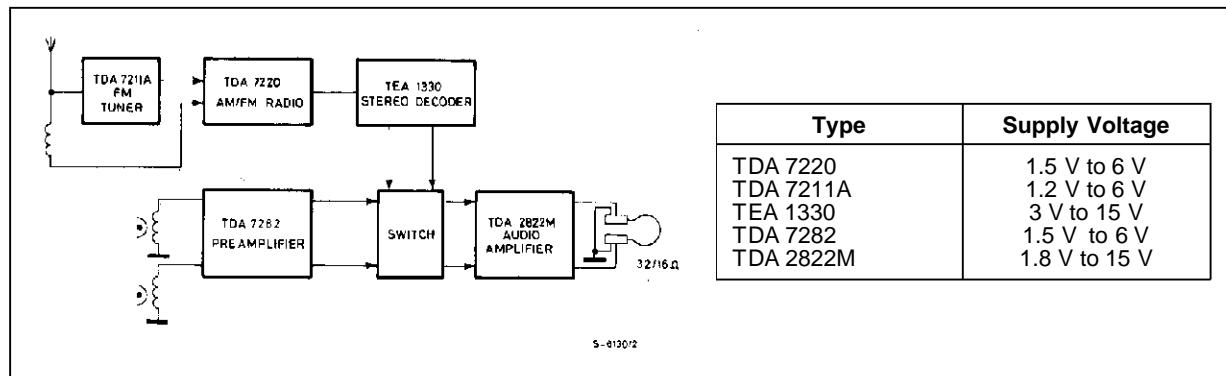
**Figure 17 :** Application in Portable Radio Receivers



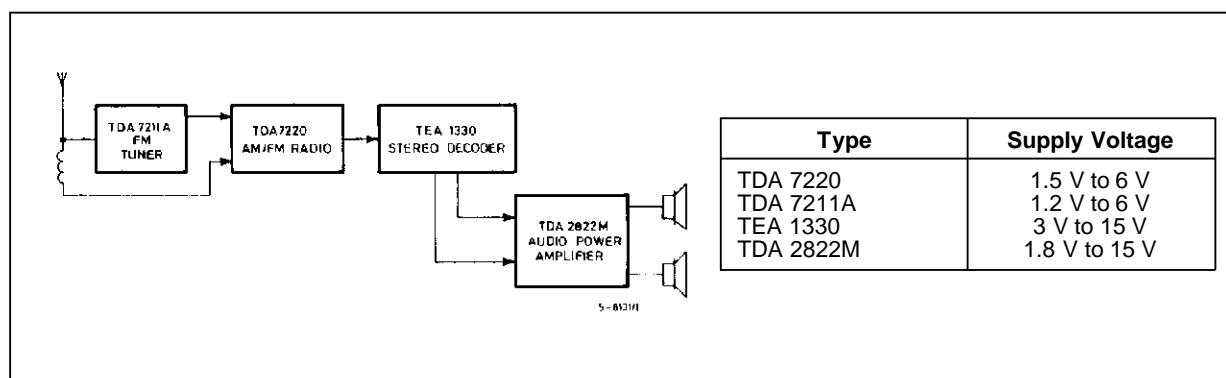
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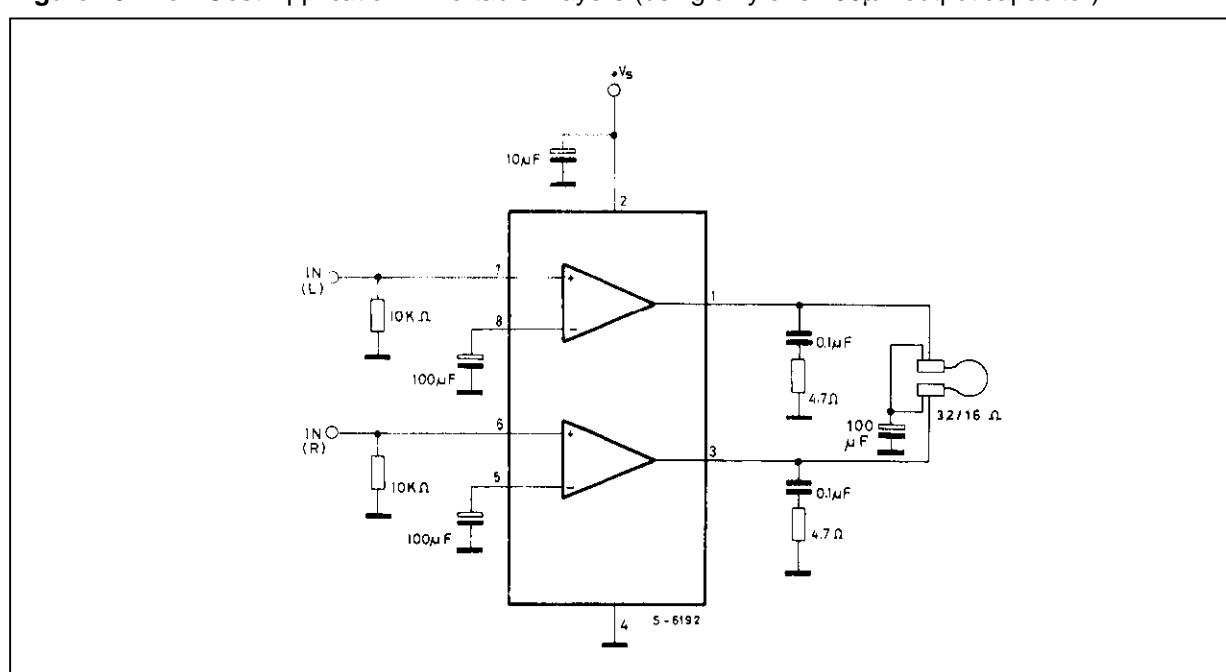
**Figure 18 : Portable Radio Cassette Players**



**Figure 19 : Portable Stereo Radios**

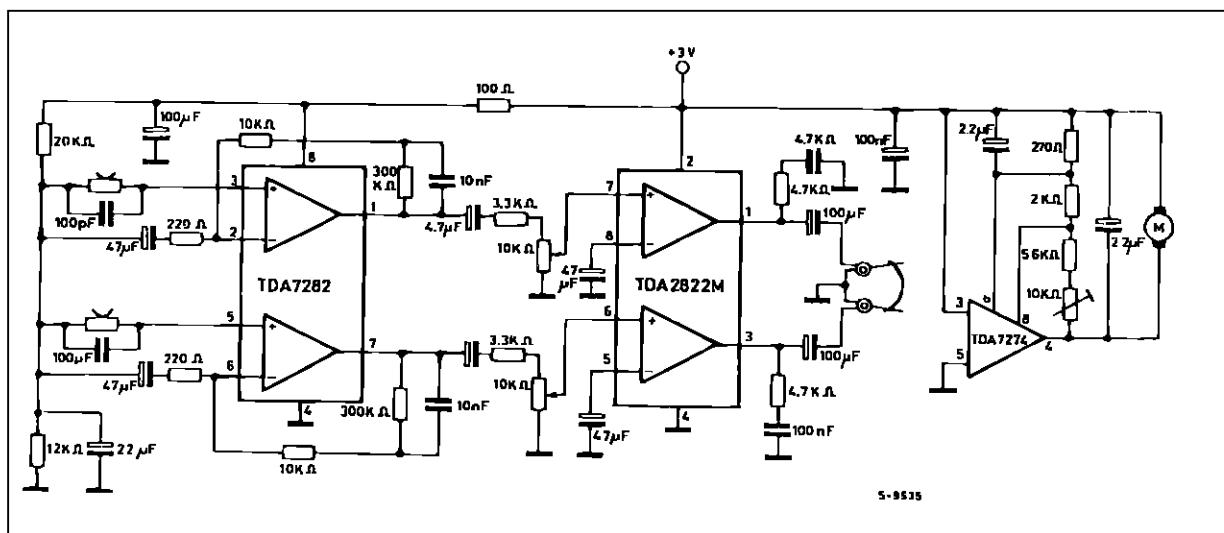


**Figure 20 : Low Cost Application in Portable Players (using only one 100μF output capacitor)**



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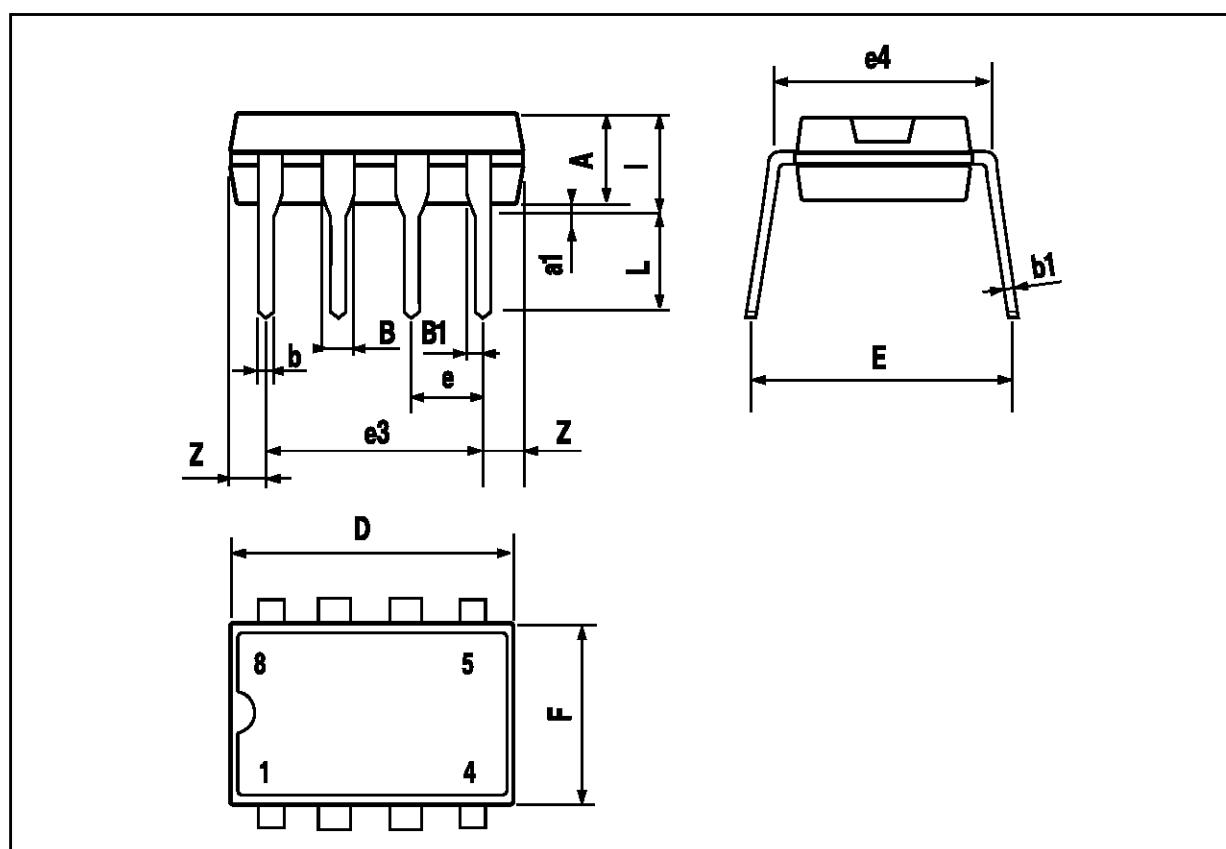
Figure 21 : 3V Stereo Cassette Player with Motot Speed Control



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### MINIDIP PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
I			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060



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